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INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)		Application Number	10/708,223
		Filing Date	02/17/2004
		First Named Inventor	Ming-Dou Ker
		Group Art Unit	
		Examiner Name	
Sheet 1 of 1	Attorney Docket Number	SISP0008USA	

OTHER PRIOR ART -- NON PATENT LITERATURE DOCUMENTS			
Examiner Initials ¹	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T ²
S	1	H. NEUTEBOOM, B.M. J. KUP, M. JANSSENS; A DSP-based hearing instrument IC; IEEE Journal of Solid-State Circuits, Nov. 1997; page 1790 - page 1806; VOL. 32.	
D	2	H. BANBA, H. SHIGA, A. UMEZAWA, T. MIYABA, T. TANZAWA, S. ATSUMI, K. SAKUI; A CMOS bandgap reference circuit with sub1-V operation; IEEE Journal of Solid-State Circuits; May 1999; page 670 - page 674; VOL. 34	
D	3	G. GIUSTOLISI; A Low-Voltage Low-Power Voltage Reference Based on Subthreshold MOSFETs; IEEE Journal of Solid-State Circuits; Jan. 2003, page 151 - page 154; VOL.38, No.1	
D	4	P. MALCOVATI, F. MALOBERTI, M. PRUZZI, C. FIOCCHI; Curvature compensated BiCMOS bandgap with 1-V supply voltage; IEEE Journal of Solid-State Circuits; July 2001; page 52 - page55; VOL.36, No.7	
D	5	YUEMING JIANG, EDWARD K.F. LEE; A 1.2 V bandgap reference based on transimpedance amplifier; ISCAS 2000-IEEE international symposium on Circuits and Systems; May 23-31, 2000; page 261 - page 264	
D	6	SHU-YUAN CHIN, CHUNG-YU WU, A New Type of Curvature-Compensated CMOS Bandgap Voltage Reference; VLSITSA; 1991; page 398 - page 402	
D	7	KA NANG LEUNG, IEEE, PHILIP K. T. MOK; A Sub-1-V 15-ppm/°C CMOS Bandgap Voltage Reference without Requiring Low Threshold Voltage Device; IEEE Journal of Solid-State Circuits; April 2002; page 526 - page 530; VOL.37, No.4	

Examiner Signature	Riley	Date Considered	Dec 04
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